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# Spin-polarized electronic states and atomic reconstructions at the antiperovskite $Sr_3SnO(001)$ polar surfaces

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We report a first-principles investigation of the atomic and electronic properties at the perfect and defective (001) surfaces of the antiperovskite Sr<sub>3</sub>SnO. We first performed a thermodynamical study of the atomic structure terminations and demonstrated that SrSn-terminated surfaces should be the most stable one, either with a perfect  $(1 \times 1)$  structure or with a  $(2 \times 1)$  reconstruction induced by the formation of Sn vacancies. We detailed the surface gap states obtained for these surfaces, which we compare with those of other surface terminations, also having relatively low energies. These gap states, located near the Fermi level, could have a major contribution to the transport properties. Due to the lack of inversion symmetry associated with the surface, we predict that they also experience spin splittings, an important property for spinorbitronic applications. Finally, we found that Sr<sub>2</sub>O-terminated surfaces could display a ferromagnetic ordering resulting from the population of 4d orbitals of Sr atoms at the surface and that this could lead to the formation of a spin-polarized two-dimensional electron gas.

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#### INTRODUCTION I.

Antiperovskites, also known as inverse perovskites, 10 possess the same crystallographic structure as normal 11 perovskites, but with cations and anions having inverted 12 their positions [1]. Following the fame of normal 13 perovskite compounds and the increased richness of their 14 interface and surface properties in nanostructures [2–4]. 15 it is now considered that studying antiperovskites could 16 enable to enlarge again more the range of applications [5, 17 6] and of material candidates to display fundamental 18 quantum properties, such as superconductivity [7] or 19 topological electronic structures [8–10]. Understanding, 20 functionalizing and optimizing these properties in a new 21 class of materials requires extensive efforts to characterize 22 their heterostructures and to develop an engineering of 23 defects, surfaces and interfaces [11]. 24

25 example of an antiperovskite that shows good promises. 26 It has been predicted to be a 3D Dirac semimetal 27 with a band structure having 6 Dirac cones along 28 the  $\Gamma$ -X directions [13]. This material is formerly 29 classified as a topological crystalline insulator [14, 15], 30 that is, it displays surface states in the gap which 31 are preserved by crystal inversion symmetry [16], or 32 as a higher-order topological insulator displaying hinge 33 states [17]. Recently, a superconducting behavior below 34 temperature  $T \simeq 5$  K has been evidenced in Sr-35 deficient  $Sr_3SnO$  antiperovskites [18–20] and some hints 36 of a ferromagnetic ordering have been attributed to the 37 possible presence of oxygen vacancies [21]. 38

 $Sr_3SnO$  possesses a perovskite structure with  $Sn^{4-}$ 30 and  $O^{2-}$  anions occupying respectively cuboctahedral 40 <sup>41</sup> and octahedral atomic sites, formed by the sublattice of  $_{42}$  Sr<sup>2+</sup> cations [22]. The anionic nature of Sn elements  $_{78}$  them have been performed by combining first-principles <sup>43</sup> has been evidenced by Mössbauer spectroscopy in both <sup>79</sup> calculations and tight-binding models in order to address

<sup>44</sup> stoichiometric and Sr-deficient  $Sr_3SnO$  compounds [20]. 45 It has also been confirmed by x-ray photoelectron <sup>46</sup> spectroscopy (XPS), while some signatures of neutral 47 or cationic Sn atoms near the surface were also <sup>48</sup> evidenced [22]. This finding can be related to the report <sup>49</sup> of possible closely-neutral Sn ions in the vicinity of a  $Ca_3SnO$  surface [23]. 50

The hypothetic  $[Sr^{2+}]_3Sn^{4-}O^{2-}$  compound would 51  $_{52}$  display in consequences an alternation of  $(SrSn)^{2-}$ <sup>53</sup> and  $(Sr_2O)^{2+}$  polar (001) atomic layers and a dipole 54 moment normal to the surfaces, thus corresponding to <sup>55</sup> surfaces of "type 3", according to the classification <sup>56</sup> proposed by Tasker [24]. Conserving the bulk structure, 57 such a surface would be associated with the creation 58 of an internal electric field and to the divergence of 59 the electrostatic potential as a function of the film  $_{60}$  thickness, unless a charge transfer of  $\pm 1$  electron First-time grown in 1980 [12], Sr<sub>3</sub>SnO is a good <sup>61</sup> per formula unit is transferred to the surface [25].  $_{62}$  It can thus be expected that growing  $Sr_3SnO(001)$ 63 thin films could lead to electronic reconstructions, on <sup>64</sup> the basis of a polar catastrophe scenario [26, 27]. 65 or atomic reconstructions with the stabilization of 66 structural defects such as vacancies. Due to the <sup>67</sup> particular structure of antiperovskites and its predicted 68 bulk band gap of a few tenths of meV, the properties 69 of Sr<sub>3</sub>SnO are expected to be very sensitive to the 70 growth conditions and to its stoichiometry [20, 21]. 71 Sr<sub>3</sub>SnO and similar compounds have already been 72 grown epitaxially on different substrates such as yttria-<sup>73</sup> stabilized zirconia (YSZ)(001), LaAlO<sub>3</sub>(001), or even <sup>74</sup> technologically-adapted substrates such as Si(001) using <sup>75</sup> a YSZ buffer layer [21, 22, 28, 29]. To our knowledge, only <sup>76</sup> (001)-oriented surfaces have been studied experimentally.

> 77 Concerning the theoretical studies on Sr<sub>3</sub>SnO, most of

<sup>80</sup> the topological nature of this material [14, 15, 17]. These <sup>117</sup> different slab geometries and including a vacuum layer 81 83 thanks to first-principles calculations. 85

86 87 Sr<sub>3</sub>SnO, a candidate topological crystalline insulator, 124 this paper have been obtained using more-convenient <sup>88</sup> are polar surfaces for which the impact of possible <sup>125</sup> symmetric slabs, terminated by two equivalent surfaces <sup>89</sup> electronic/chemical reconstructions on the protected <sup>126</sup> and with a thickness of 21 atomic monolayers (MLs), <sup>90</sup> surface states is not well understood.  $_{91}$  surface structures could potentially lead to new ground  $_{128}$  Sr<sub>2</sub>O or SrSn ML (labeled 10.5 in the following). An <sup>92</sup> states such as magnetic state, which has not previously <sup>129</sup> example of such structure can be viewed in Fig. 1(a) <sup>93</sup> been taken into account. Either conventional electronic <sup>130</sup> for the case of a Sr<sub>2</sub>O-terminated surface. <sup>94</sup> reconstruction or magnetic transition could have a <sup>131</sup> differences obtained with such slab, if compared with an <sup>95</sup> decisive effect on the true realization of surface states <sup>132</sup> asymmetric slab, containing two non-equivalent surfaces <sup>96</sup> in these compounds. In consequence, we propose a <sup>133</sup> [Fig. 1(b)], are also discussed throughout the paper, and 97 detailed study based on *ab initio* calculations of the 134 more particularly detailed in Appendix B. We show in 98 Sr<sub>3</sub>SnO(001) surfaces. We will first describe electronic <sup>135</sup> particular that, if the electronic reconstructions discussed <sup>99</sup> reconstructions which appear at the perfect surfaces, <sup>136</sup> in this paper have a different origin (off-stoichiometry or <sup>100</sup> with either a Sr<sub>2</sub>O or a SrSn termination. The main <sup>137</sup> polar catastrophe) depending on the chosen geometry, <sup>101</sup> properties of these surfaces will be compared with <sup>138</sup> they finally result in similar and robust surface states, <sup>102</sup> defective terminations in which vacancies or adatoms <sup>139</sup> with almost equal occupancy; only the symmetries induce <sup>103</sup> introduce atomic reconstructions and charge doping. <sup>140</sup> noticeable changes, in the possibility that some bands A discussion of the relative stability of each surface <sup>141</sup> will have to undergo spin-splitting lift of degeneracies. 104 105 termination is also provided.

#### II. CALCULATION DETAILS

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We performed first-principles calculations based on 147 107 <sup>108</sup> the density functional theory (DFT) by using the Vienna *ab initio* software package (VASP) [32, 33]. 109 We employed the projector augmented wave (PAW) 110 <sup>111</sup> method [34], a cut-off energy of 550 eV and the <sup>151</sup> ML. <sup>112</sup> generalized-gradient approximation of the exchange-<sup>113</sup> correlation energy proposed by Perdew, Burke and <sup>114</sup> Ernzerhof and revised for solids (GGA-PBESol) [35].

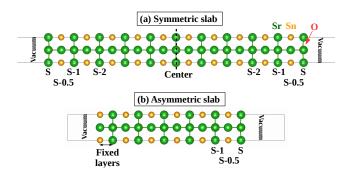


FIG. 1. (a) Symmetric and non-stoichiometric  $(1 \times 1 \times 10.5)$ (b) Asymmetric and stoichiometric slab with a  $Sr_2O$  surface opposite surface is fixed to the bulk interplane distance.

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works have however only considered ideal structures with 118 with a thickness of at least 15 Å to separate the two <sup>82</sup> perfect surfaces. More recently, the question of structural <sup>119</sup> surfaces. These slab calculations can be compared to the defects in the bulk crystal [30] and of perfect (001) 120 calculations of bulk properties described in Appendix A. surfaces [31] have been addressed separately and fully 121 The in-plane lattice parameters have been fixed to <sup>122</sup> the calculated bulk equilibrium value of  $a_0(Sr_3SnO) =$ To summarize, the surfaces of the antiperovskite 123 5.1 Å. Unless otherwise stated, the results presented in Those new  $_{127}$  that is 10 formula units (f.u.) of Sr<sub>3</sub>SnO plus an added Some

> The in-plane directions of the first Brillouin zone were 142 <sup>143</sup> sampled with a Monkhorst-Pack grid [36] of  $15 \times 15$ <sup>144</sup> vectors, for a supercell with  $1 \times 1$  lateral dimensions.

> Bader charges have been calculated using the Bader 145 <sup>146</sup> charge analysis code described in Ref. [37].

> In the following, the (S) and (S-0.5) denominations <sup>148</sup> correspond respectively to the surface and subsurface <sup>149</sup> atomic monolayers (MLs). The labels  $[Sr]_O$  and  $[Sr]_{Sn}$  are 150 given for Sr atoms located in a  $Sr_2O(001)$  or SrSn(001)

#### **UNRECONSTRUCTED (001) SURFACES** III. 152

In this section, we will describe the atomic and 153 <sup>154</sup> electronic structure of unreconstructed (001) surfaces <sup>155</sup> of Sr<sub>3</sub>SnO. For the calculations, we used symmetric  $_{156}$  1  $\times$  1  $\times$  10.5 slabs terminated by two equivalent surfaces  $_{157}$  with the ideal  $Sr_2O$  or SrSn termination, as shown in 158 Fig. 1(a).

#### $Sr_2O(001)$ -terminated surface А.

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a. Atomic structure: At the  $Sr_2O$ -terminated 160 <sup>161</sup> surface, the interlayer distance is reduced to 2.43 Å slab with two non-equivalent  $Sr_2O$ -terminated surfaces and 162 between the surface (S) and subsurface (S-0.5) layers,  $_{163}$  *i.e.* by -4.7% if we compare with the bulk inter-atomic-(S). The distance between the two atomic layers at the 164 layer distance of 2.55 Å. The calculated distortions <sup>165</sup> then display oscillations in the following layers, with <sup>166</sup> reduced magnitude (the interlayer distance is 2.59 Å As shown in Fig. 1, we performed direct calculations of  $_{167}$  (+1.4%) between the layers S-0.5 and S-1) up to the  $_{116}$  the electronic properties of Sr<sub>3</sub>SnO(001) surfaces using  $_{168}$  center of the slab, where we recover the bulk lattice

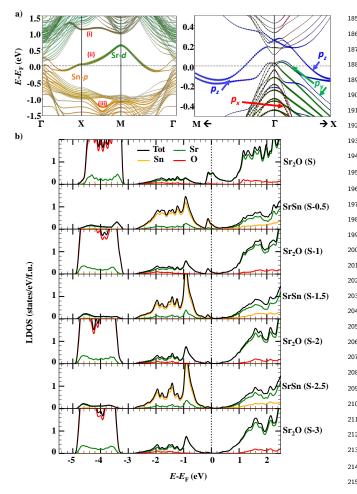


FIG. 2. (a) and structure calculated with a symmetric slab and nonmagnetic Sr<sub>2</sub>O-terminated surfaces The size of the colored circles is proportional to the contribution of each surface atom: On the left panel, the colors correspond to the  $[Sr]_O$  (green), O (red),  $[Sr]_{Sn}$  (cyan) and Sn (orange) atoms the nearest from the surfaces, while on the right pannel, we display a zoom with the detailed of the surface  $\operatorname{Sn-}p$  bands of states (LDOS).

<sup>169</sup> parameter. Due to the different oxidation degree of each <sup>227</sup> near  $\Gamma$ . <sup>170</sup> atom and the polar nature of Sr<sub>3</sub>SnO, we also observe a <sup>228</sup> 171 172 <sup>173</sup> layer. Such buckling is already 10 times smaller in the <sup>231</sup> nature, near the  $\Gamma$  point. 174 S-1 layer.

*b*. Electronic *structure:* The calculated 175 176 177 178 we can recover the bulk states forming parabolas <sup>237</sup> M points. 179 centred around the  $\Gamma$  point, while the LDOS in atomic 238 180 181 182 from the layer (S-3)), are very similar to those of the bulk 240 contributions of the surface states, we see a change of 183 [see Fig. 11]. Clear gap states, labeled (ii) in the band  $_{241}$  the spin orientation as a function of the wavevector k: <sup>184</sup> structure, appear near the Fermi level. These gap states <sup>242</sup> Always orientated in-plane, they are aligned along the

185 are expected to primarly participate to the conduction and it can be noticed that their intensity decreases when 186 going toward the center of the slab, to reach an almost 187 0 value at the layer (S-3). The integration of the total 188 189 DOS between  $E_{\rm F} - 0.25$  eV and  $E_{\rm F}$  is equal to 1.1 state, <sup>190</sup> which will be occupied by electrons. Another surface <sup>191</sup> state, labeled (i), can be observed around 1.2 eV above the Fermi energy, with a mix of  $[Sr]_O$  and O character, 192 <sup>193</sup> while lower Sn-p states (iii), also with a strong surface contribution can finally be noticed below  $E_{\rm F} - 1$  eV. 194

The following observations are also made.

First of all, p-d band anticrossings, appearing along 196 the  $\Gamma$ -X direction in the bulk band structure [see 197 Appendix A], are now located above the Fermi level. 198 In the bulk, these crossings happen at the intersection between  $\operatorname{Sr-}d_{y^2-z^2}$  and  $\operatorname{Sn-}p_y + ip_z$  (for X of coordinates 200 (0.5,0,0) and they are generally associated with pseudo-Dirac points [13, 38, 39]. In the vicinity of a surface, they cannot be Dirac points, as the inversion symmetry 203 would not be preserved anymore; their band character 204 is moreover slightly changed, as, because of the surface, 205 the y[010] and z[001] directions are also not equivalent, 206 which consequently induces a lift of degeneracy of the p207 states. 208

The second interesting point is that the bands (ii), 209 forming the surface gap states near the Fermi level, <sup>211</sup> display a different band character as a function of the 212 considered wave vector k: These bands have mainly <sup>213</sup> a Sr(S)- $d_{xz}$ ,  $d_{yz}$  character between the X( $\frac{1}{2}$ , 0, 0) and <sup>214</sup> M( $\frac{1}{2}, \frac{1}{2}, 0$ ) points, a Sn(S-0.5)- $p_z$  near the  $\Gamma(0,0,0)$  point, 215 and a mixed character otherwise. The two sets of bands <sup>216</sup> corresponding to the surface states start changing their  $_{217}$  character around the X/2 and M/2 points, where these <sup>218</sup> bands display a minimum. With this difference of orbital 219 contributions, we also observe a different localization in <sup>220</sup> real space. While these states between X and M are 221 mostly unoccupied and possess a strong contribution <sup>222</sup> coming from Sr atoms located in the surface layer (S), contributions around the  $\Gamma$  point. (b) Layer-resolved densities 223 they tend to be more delocalized and they spread in the  $_{224}$  whole slab when having a Sn band character near the  $\Gamma$ <sup>225</sup> point. This charge delocalization can be seen as a result  $_{226}$  of the  $p_z$  nature of the band and of the narrow band gap

A third point is that, due to the position of the cation-oxygen buckling along the z[001] direction, which 229 Fermi level, not only the aforementioned surface bands is  $\Delta z = \langle z(\text{cation}) \rangle - \langle z(\text{anion}) \rangle = 0.173$  Å at the surface 230 are crossing it, but also Sn- $p_y$  bands, with a clear bulk

232 Finally, as it is shown in Appendix C, the band band 233 structure only slightly depends on the spin-orbit structure and the layer-resolved densities of states 234 interaction, which only induces a small lift of degeneracy, (LDOS) for the slab having a Sr<sub>2</sub>O-terminated surface <sup>235</sup> splitting the surface states near the Fermi level into two are given in Figs. 2(a) and 2(b). In the band structure, 226 sets of two non-spin-polarized bands around the X and

c. Spin textures Still using a symmetric slab, we monolayers located in the center of the slab (starting 239 found out that, associated with the change of the orbital  $_{243}$  [010] direction between X/2 and X and along the [100]  $_{272}$  (ii), are fully degenerate, a NM state is more stable, <sup>244</sup> direction along the X-M direction. For the symmetric <sup>273</sup> while lifting some degeneracy (using an asymmetric slab <sup>245</sup> slab, no spin splitting was observed. On the contrary, <sup>274</sup> or adding the spin-orbit interaction) implies that fully 246 using an asymmetric slab, which lacks the inversion 275 occupying one set of two-bands by one charge of a 247 symmetry, as a real surface would, we observe such 276 given spin is more favorable, inducing in consequence the <sup>248</sup> spin splittings in the band structures, as shown in <sup>277</sup> emergence of a ferromagnetic ordering. <sup>249</sup> Fig. 3, which give spin textures consistent with a Rashba-<sup>278</sup> For the symmetric slab, the corresponding total  $_{250}$  like spin-orbit effect, with a dominant linear-in-k term  $_{279}$  magnetic moment is orientated along the [111] direction. <sup>251</sup> around the X and M points (with spin vectors tangent <sup>280</sup> while it is along the [001] direction with the asymmetric  $_{252}$  to the energy contour) and a non-negligeable cubic  $_{281}$  slab. In both cases, it has a magnitude of 0.84  $\mu_{\rm B}$  $_{253}$  character around the  $\Gamma$  point. The effective masses and  $_{282}$  per surface f.u. The magnetic state appears to be a 254 splitting parameters calculated around the X and M 283 result of the charge reorganization, which results in the <sup>255</sup> points are given in Table II of Appendix B.

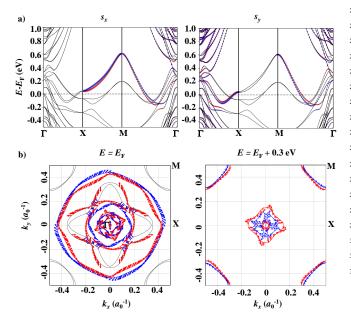


FIG. 3. Spin configurations at the Sr<sub>2</sub>O-terminated surface as calculated with an asymmetric slab: (a) Spin-projected band structures and (b) iso-energy projections in the 2D 1<sup>st</sup> Brillouin zone, with the associated spin textures. Blue and red colors help to distinguish between the two splitted bands with opposite spin directions. Grey lines correspond to bands for which the atoms at the considered surface do not contribute.

d. Magnetic ordering: Up to now, we considered a 256 perfect  $Sr_2O$  surface with the same nonmagnetic (NM) 257 behavior as bulk Sr<sub>3</sub>SnO compound. We also found it is 258 possible to stabilize a ferromagnetic (FM) state, leading 259 to the band structures shown in Figs 4(a) and 4(b); 260 261 this FM state is more stable than the NM state, with  $_{\rm 262}$  an energy difference per surface f.u.  $\Delta E~=~E_{\rm FM}~ _{263} E_{\rm NM} = -0.43 \text{ meV } a_0^{-2}$ . We would like to mention that 264 it was only possible to calculate the above-mentioned <sup>265</sup> magnetic state by adding the spin-orbit interaction. <sup>266</sup> Using the asymmetric slab, even in the absence of the <sup>267</sup> spin-orbit interaction, we were able to recover a similar  $_{268}$  magnetic state, with a difference of total energy per  $_{303}$ <sup>269</sup> surface f.u. separating the FM and NM state of  $\Delta E = {}_{304}$  spin expectation values are orientated parallel to the <sup>270</sup> -1.42 meV  $a_0^{-2}$ . From this observation, we can only infer  ${}_{305}$  total spin magnetic moment, *i.e.* along the [111] 271 the hypothesis that when the four surface bands, labeled 306 or [001] direction, respectively for the symmetric or

 $_{284}$  population of Sr-4d orbitals in the surface layer, as it  $_{285}$  can be seen in Figs 4(a) and Fig 4(c), in the case of a 286 symmetric slab. The calculated total magnetic moment <sup>287</sup> agrees with the redistribution of 2 electrons (one on each 288 surface) resulting from the absence of a  $(SrSn)^{2-}$  layer. 289 As it can be seen in Fig. 4(c), the Sr-4d orbitals are not <sup>290</sup> strongly localized near the atom nucleus and the spin <sup>291</sup> density strongly extends in the vacuum; it results that <sup>292</sup> the calculated spin magnetic moment calculated from 293 the integration of states projected in the atomic sphere centered on a surface Sr atom is only 0.05  $\mu_{\rm B}/{\rm atom}$ . 294

Concerning the band structure, due to the magnetic 295 exchange interaction, the ferromagnetic ordering leads to 296 <sup>297</sup> a band spin splitting which is of approximately 0.8 eV for 298 k vectors for wavectors in the X-M direction, as it can be sen in Fig. 4(b). The band structure now displays bands 299 <sup>300</sup> crossing the Fermi level, which are linked to minority-spin <sup>301</sup> electron pocket around the  $\Gamma$  point and to a majority-spin <sup>302</sup> hole pocket around the M point.

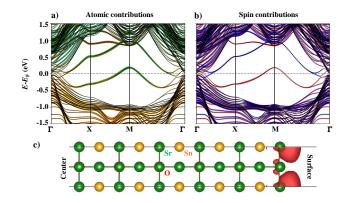


FIG. 4. Band structure of the perfect Sr<sub>2</sub>O-terminated surface calculated with the spin-orbit interaction and for a magnetic state. a) The contribution of the atoms of the surface is given by the colored circles following the same color code than in Fig. 2. b) The sign of the spin projection  $s_z$ (with the quantization axis z along the [001] direction) on the band structure and c) the corresponding spin density is given in red for positive values and blue for negative values.

When the surfaces are in the FM states, the

<sup>307</sup> asymmetric slab, showing a dominance of the magnetic exchange interaction over the spin-orbit effects. With 308 the asymmetric slab, small values of spin projections, 309 310 reminiscent of the spin-orbit-induced spin textures, can be observed along the x[100] and y[010] directions only  $_{312}$  for bulk bands, that are near the  $\Gamma$  point or at energies  $_{313}$  below  $E_{\rm F} - 1$  eV.

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#### В. SrSn(001)-terminated surface

a. Atomic *structure:* The interlayer distance 315 316 between the surface (S) and subsurface (S - 0.5)<sup>317</sup> monolayer is calculated to 2.46 Å, which corresponds to  $_{318}$  a reduction of -3.5%, that is lower than for the  $Sr_2O$ termination, on the contrary to an almost two-times 319 larger cation-anion (Sr-Sn) buckling (+0.39 Å). 320

b. Electronic structure: Analyzing the electronic 321 structure of the SrSn-terminated surface [Fig. 5], we can 322 observe again the appearance of different surface gap 323 states. These gap states more precisely correspond to 324 depleting  $\operatorname{Sn-}p$  states at the surface, which creates a band 325 326 bending and a shift of the bulk peak, originally located  $_{327}$  at  $E_{\rm F} - 1$  eV, upward in energy, to the Fermi energy. 328 From the LDOS, we can thus observe a peak of high 329 density at the Fermi energy, resulting from bands with  $_{330}$  low dispersion. Around the  $\Gamma$  point, we indeed observe three sets of bands near the Fermi level, which correspond 331 to  $\operatorname{Sn-}p$  surface states. One of these sets of bands, labeled 332 333 (i), stays close to the Fermi level and in the bulk band gap away of  $\Gamma$ ; it possesses a majoritarily  $p_u$  character 334  $_{335}$  in the  $\Gamma$ -X direction, with a low dispersion, while it  $_{336}$  has a large  $p_z$  contribution along the directions X-M- $_{337}$   $\Gamma$ . The second set of band, which is more dispersive  $_{338}$  than the first one, possesses on the contrary a  $p_z$ ,  $p_y$ <sup>339</sup> and  $p_x + p_y$  character, respectively along the  $\Gamma$ -X, X-M  $_{340}$  and M- $\Gamma$  directions. The integration of the total DOS  $_{341}$  between  $E_{\rm F}$  and  $E_{\rm F} + 0.4$  eV indicates the formation of 342 0.9 holes per surface, distributed approximately over five 343 atomic layers.

Contrary to the NM  $Sr_2O$  surface for which the spin-344 orbit interaction leads to almost no visible effects on 345 346 the electronic structure, it is important to note that for 362 that for this surface termination, we only predict the 347 this surface termination, the band gap between the set 363 appeance of an almost zero total spin magnetic moment 349 0.2 eV as a direct result of the spin-orbit coupling. At 365 it is possible to stabilize a magnetic state, but its origin 350 this high-symmetry point, we thus observe an avoiding 366 certainly comes from the presence of the second and non-351 hybridization. Finally, the third set of bands, labeled 368 also primarily magnetized. 352 (iii) and corresponding to  $\text{Sn-}p_x$  bands, displays a more  $_{369}$  c. Spin textures As for the  $\text{Sr}_2\text{O}$ -terminated surface, 353 354 355 356 <sup>357</sup> highest in energy and less occupied, displays a minimum <sup>373</sup> of Rashba-like spin splittings, the values of which have 358 at the X point, and a maximum, corresponding to a hole 374 been calculated using the spin-projected band structures <sup>359</sup> pocket at the M point, certainly resulting from the charge <sup>375</sup> of Fig. 6(a) and are given in Table II in Appendix B. <sub>360</sub> reorganization induced by the nonstoichiometry of the <sub>376</sub> We can notice that these values are of the same order of <sup>361</sup> structure. In addition, it is also important to mention <sup>377</sup> magnitude than for the other surface termination. Also

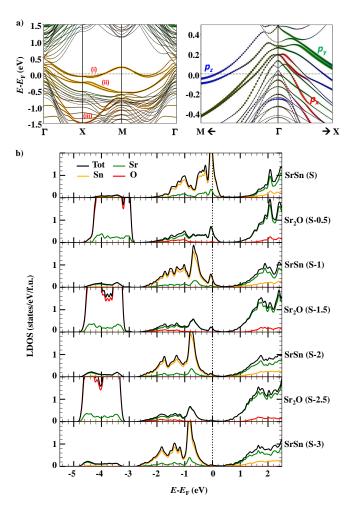


FIG. 5. (a) Band structure calculated for the SrSnterminated surface. The size of the colored circles is proportional to the contribution of each surface atom: On the left panel, the colors correspond to the  $[Sr]_{\Omega}$  (green), O (red),  $[Sr]_{Sn}$  (cvan) and Sn (orange) atoms the nearest from the surfaces, while on the right pannel, we display a zoom with the detailed of the surface Sn-p bands contributions around the  $\Gamma$  point. (b) Layer-resolved densities of states (LDOS).

of states (i) and (ii) at the X point is increased up to  $_{364}$  of 0.04  $\mu_B$  per surface f.u. Using an asymmetric slab, of the bands which is accompanied by a strong  $p_u + p_z$  367 physical surface (with the Sr<sub>2</sub>O termination), which is

dispersive behavior with a minimum at  $E_{\rm F}$  - 1.5 eV at the 370 the spins at the SrSn surface are orientated in-plane X point. Both sets of bands (i) and (ii) cross the Fermi 371 and along a direction perpendicular to the wavevector level in the  $\Gamma$ -X and  $\Gamma$ -M directions, while the set (i), the  $_{372}$  k. Using an asymmetric slab induces the appearance 380 381

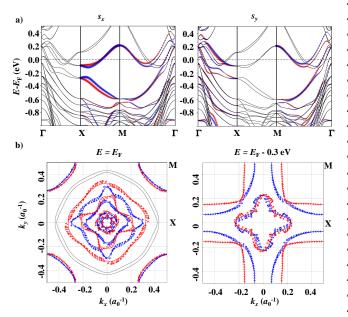


FIG. 6. Spin configurations at the SrSn-terminated surface as calculated with an asymmetric slab: (a) Spin-projected band structures and (b) Iso-energy projections in the 2D 1<sup>st</sup> Brillouin zone, with the associated spin textures. Blue and red colors help to distinguish between the two splitted bands with opposite spin directions. Grey lines correspond to bands for which the atoms at the considered surface do not contribute.

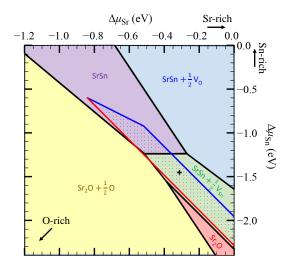
#### **RECONSTRUCTED (001) SURFACES** 386

In the previous section, we considered perfect (001)387  $_{388}$  surface terminations of Sr<sub>3</sub>SnO, *i.e.* Sr<sub>2</sub>O and SrSn, and we discussed the electronic modifications which appears 389 in the vicinity of these surfaces. We will now verify 390 which surface termination should be the most stable and 391 <sup>392</sup> if atomic reconstruction induced by the presence of point <sup>393</sup> defects could be favored. When stable, we will describe <sup>394</sup> the effects of these defects on the electronic and magnetic <sup>395</sup> properties. The method to calculate the surface stability is explained in Appendix D. The properties described in 396 <sup>397</sup> this section have been calculated using  $(2 \times 1 \times 10.5)$  slabs; <sup>398</sup> as explained in Appendix D 3, as they were found more <sup>399</sup> stable than  $(\sqrt{2} \times \sqrt{2}) R45^\circ$ .

a. Stability of the surface terminations: The figure 7 400 401 gives the phase diagram of the surface termination 402 stability as a function of the variations of the chemical

<sup>378</sup> similarly to the Sr<sub>2</sub>O surface, we can see from the spin <sup>403</sup> potentials of Sr and Sn atoms. In a reasonable range of textures presented in Fig. 6(b) again mostly a linear 404 chemical potentials, we see that 5 different terminations Rashba behavior related to tangential spins around the 405 can be stabilized. If we restrict ourselves to the chemical X and M points, while cubic contributions are expected  $_{406}$  potentials fixed so that the bulk Sr<sub>3</sub>SnO can be grown, to be responsible of the deviation from this behavior near 407 we only have to consider the values matching with the  $_{408}$  the  $\Gamma$  point. Large increase of the spin splitting can be  $_{408}$  dotted area in Fig. 7 [See Appendix D for more details]; <sup>384</sup> noticed on the spin textures, for wavevectors for which <sup>409</sup> in that case, we can first conclude that, according to 385 the bands (i) and (ii) are the closest one from each other. 410 our calculations, there is in principle a higher probability <sup>411</sup> to obtain a SrSn-terminated surface, with potentially  $_{412}$  Sn vacancies (V<sub>Sn</sub>), leading ultimately to a SrSn<sub>0.5</sub>  $_{413}$  surface (labeled "SrSn+ $\frac{1}{2}V_{\rm Sn}$ "). The formation of Sr<sub>2</sub>O-<sup>414</sup> terminated surfaces, however, appear also realistic if we 415 consider that their domain of stability are close to the 416 limit of stability of the bulk and that our results may <sup>417</sup> depend on the chosen exchange-correlation functional; 418 in this latter case, we can see from Fig. 7 that the 419 adsorption of oxygen atoms may lead to more stable <sup>420</sup> Sr<sub>2</sub>O<sub>1.5</sub> terminations (labeled "Sr<sub>2</sub>O+ $\frac{1}{2}$ O") in oxygen-421 rich conditions.

> To give a more quantitative idea of the energy 422 423 differences between each surface termination, we can <sup>424</sup> consider the averaged value of chemical potentials for  $_{425}$  which bulk Sr<sub>3</sub>SnO is stable, *i.e.* the point of coordinates  $_{\rm 426}~\Delta\mu_{\rm Sr}~=~-0.341~{\rm eV},~\Delta\mu_{\rm Sn}~=~-1.440~{\rm eV},~{\rm represented}$ 427 by a "+" sign in Figs. 7 and 15: With these values 428 of chemical potentials, the energy difference between  $_{\rm 429}$  the perfect Sr\_2O and SrSn terminated surfaces  $\Delta\gamma_{\rm S}$  =  $\gamma_{\rm S=Sr_2O} - \gamma_{\rm S=SrSn}$  is calculated to be almost 0 eV/surface <sup>431</sup> formula unit and the calculated formation energy of a Sn  $_{432}$  vacancy at the SrSn surface is  $E_{\rm d}(V_{\rm Sn}) = -0.21$  eV per <sup>433</sup> defect [See Appendix D 3].



Stability phase diagram for a  $Sr_3SnO(001)$ FIG. 7. The dotted area corresponds to the domain of surface. chemical potentials for which Sr<sub>3</sub>SnO bulk can be synthetized [see Fig. 15 in Appendix D]. Each colored area corresponds to a chemical-potential domain for which a given surface termination is the most stable, *i.e.* displays the lowest surface energy  $\gamma_{\rm S}$  as calculated using Eq. D5.

b. Induced atomic distortions: The introduction of 467 Sn deficiency, indeed seems a priori to present more 434 a Sn vacancy at the SrSn-terminated surface does not 468 similarities with the Sr<sub>2</sub>O termination. 436 437 439  $_{440}$  the vacancy, by 0.38 Å along the x[100] direction. The  $_{473}$  are crossing the Fermi level. We only calculated a total 441  $_{442}$  adatom is on the contrary strongly changed (-0.17 å) 443 with an inversion of its sign. The atomic structures 444 calculated for these two defective surfaces are shown in 475 <sup>445</sup> the Appendix D 3 in Fig. 16.

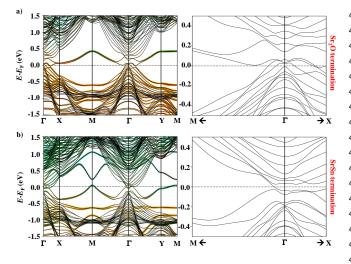


FIG. 8. Band structure of the most stable  $(2 \times 1)$  defective surfaces, with (a) a  $Sr_2O_{1.5}$  ( $Sr_2O + \frac{1}{2}O$ ) termination or (b) a  $SrSn_{0.5}$  ( $SrSn + \frac{1}{2}V_{Sn}$ ) termination. The contributions of each atom of the surface are given by the colored circles following the same color code than in Fig. 2. A zoom of the band structures around the  $\Gamma$  point is given for each surface in the right panels.

c. Induced changes in the electronic structure: 446 <sup>447</sup> Figures 8(a) and 8(b) provide the band structures for the 448 most stable  $(2 \times 1)$  defective surfaces with respectively  $_{449}$  a  $Sr_2O_{1.5}$  and  $SrSn_{0.5}$  termination. The  $Sr_2O_{1.5}$ - $_{450}$  terminated surface corresponds to a perfect (2  $\times 1)~{\rm Sr_2O}$ <sup>451</sup> surface with an oxygen adatom located on top of one <sup>452</sup> Sn atom. This surface displays a band structure very  $_{453}$  close to the one calculated for the perfect Sr<sub>2</sub>O surface <sup>454</sup> [Fig. 2(a)], except for the surface bands crossing the  $_{455}$  Fermi level for wavevectors closer from  $\Gamma$  in the  $\Gamma$ -Y and  $_{508}$  In Fig. 9 and Table I, we provide the variation in the Sn- $_{456}$   $\Gamma$ -X directions, indicating that due to the presence of the  $_{509}$  3d CLE across the different layers, referenced to the value <sup>457</sup> additional negatively-charged oxygen ion, these bands <sup>510</sup> in bulk Sr<sub>3</sub>SnO, *i.e.*  $\Delta \varepsilon_{Sn,3d} = \varepsilon_{Sn,3d}^{\text{layer}} - \varepsilon_{Sn,3d}^{\text{bulk}}$ . Overall, <sup>458</sup> tend to be less occupied. For this surface termination, <sup>511</sup> the CLEs do not deviate by more than a few hundred 459 460 461 orbitals, as represented by the red circles. 462

463 <sup>464</sup> surface [Fig. 8(b)] with its perfect counterpart [Fig. 5(a)], <sup>517</sup> charge is redistributed for the different surfaces. Similar 465 466 changed: This surface termination, certainly due to its 519 metals [42], when small amounts of electrons (holes) are

We can in

change significantly the buckling, which is calculated to 469 particular highlight the set of bands crossing the Fermi be 0.42 Å. Due to the unoccupied atomic sites created 470 level at the M point, forming a small hole pocket with by the vacancy, we also observe an in-plane distortion, 471 Sr-d character. It is also intersting to note that around with a displacement of the surface Sr atoms away from  $_{472}$  the  $\Gamma$  point, the bottom of the bulk conduction bands buckling at the Sr<sub>2</sub>O-terminated surface with an oxygen  $_{474}$  magnetic moment of 0.002  $\mu_{\rm B}$ , which is not significant.

#### BADER CHARGES AND CORE-LEVEL V. ENERGIES

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Experimentally, the surface electronic structure of 477  $Sr_3SnO(001)$  has been investigated via ARPES [29] 478 479 and XPS [22], both to map the band structure and 480 to track the atomic valence states. Thus, in this <sup>481</sup> section, we consider how the Bader charges and core-482 level energies (CLEs) are modified in perfect and <sup>483</sup> reconstructed surfaces. These quantities are provided in Table I and will allow an analysis, complementary to the 484 band structures described in Sections III and IV. 485

486 On the one hand, the formal oxidation states are obtained by subtracting calculated Bader charges to the 487 488 number of electrons of the neutral Sr atom. Bader 489 charge analysis [37] is one of the numerous methods <sup>490</sup> which allow to obtain a numerical value of the charge carried by a chemical species [40] and this will help understanding the electronic reconstructions occuring <sup>493</sup> in our systems. However, in practice, this method <sup>494</sup> depends on a specific choice of partionning of the <sup>495</sup> real-space volume and particular care has to be taken <sup>496</sup> when comparing Bader charges of bulk and surface <sup>497</sup> atoms. We chose to restrict the use of this method to <sup>498</sup> the analysis of charge occupancy on Sr atoms, which  $_{499}$  possess sufficiently localized d orbitals and for which we <sup>500</sup> calculated significant variations.

On the other hand, the CLEs are also sensitive to  $_{\rm 502}$  the local chemical and electrostatic environment and can <sup>503</sup> be probed experimentally by XPS. The binding energy  $_{504}$   $E_{\rm b}$  associated with the removal of a core electron can 505 be measured directly and, in the so-called initial-state  $_{506}$  approximation [41–43], it is equal to the opposite of the 507 CLE  $\varepsilon_{\rm c}$ , referenced to the Fermi level  $E_{\rm F}$ :

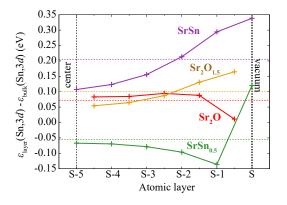
$$E_{\rm b} = -\varepsilon_{\rm c} = -(\epsilon_c - E_{\rm F}) \tag{1}$$

it is also possible to note that the surface states near  $_{512}$  of meV from the value for anionic Sn in bulk Sr<sub>3</sub>SnO, the Fermi level, which have mostly a Sn-p character for 513 showing that anionic Sn remains stable and does not every surfaces, display a visible contribution from oxygen 514 undergo a drastic change in valence state. Nevertheless,  $_{515}$  the small but systematic shifts in the Sn 3d CLEs across If we now compare the defective  $SrSn_{0.5}$ -terminated  $_{516}$  the different layers of the various slabs shed light on how we can directly see that the surface states are strongly <sup>518</sup> to CLE shifts computed for surfaces of various transition

TABLE I. Calculated properties of the  $Sr_3SnO(001)$  surfaces: Surface and averaged core-level shifts  $\Delta \varepsilon_{Sn,3d}$  and oxidation degrees estimated from the Bader charges for the Sr atoms in the surface layer. For a given defect, the calculated values are given for the structures with the lowest total energies [See Appendix D 3].

| Structure            | $\Delta \varepsilon^{\rm S}_{Sn,3d}$ | $\left<\Delta\varepsilon_{Sn,3d}\right>$ | $Q_{\rm Bader}^{\rm S}({\rm Sr})$ |  |  |  |
|----------------------|--------------------------------------|--|-----------------------------------|--|--|--|
|                      | (eV)                                 | (eV)                                     | (e)                               |  |  |  |
| Bulk                 |                                      |  |                                   |  |  |  |
| Perfect              | -                                    | 0  | +1.24                             |  |  |  |
| $Sr_2O$ termination  |                                      |  |                                   |  |  |  |
| Perfect (NM)         | 0.011                                | 0.072                                    | +0.98                             |  |  |  |
| Perfect (FM)         | -0.098                               | -0.015                                   | +1.08                             |  |  |  |
| $+\frac{1}{2}V_{Sr}$ | 0.154                                | 0.097                                    | +1.28                             |  |  |  |
| $+\frac{1}{2}V_{Sn}$ | -0.269                               | -0.182                                   | +0.81                             |  |  |  |
| $+\frac{1}{2}V_{O}$  | -0.095                               | -0.046                                   | +0.69                             |  |  |  |
| $+\frac{1}{2}O$      | 0.165                                | 0.100                                    | +1.14                             |  |  |  |
| SrSn termination     |                                      |  |                                   |  |  |  |
| Perfect              | 0.338                                | 0.205                                    | +1.30                             |  |  |  |
| $+\frac{1}{2}V_{Sr}$ | 0.438                                | 0.250                                    | +1.31                             |  |  |  |
| $+\frac{1}{2}V_{Sn}$ | 0.120                                | -0.054                                   | +1.15                             |  |  |  |
| $+\frac{1}{2}Vo$     | 0.307                                | 0.137                                    | +1.26                             |  |  |  |
|                      |                                      |  |                                   |  |  |  |

<sup>520</sup> transferred to the Sn atoms, the extra potential rigidly <sup>521</sup> shifts the valence DOS and core levels down (up) relative <sup>522</sup> to the Fermi energy, thus increasing (decreasing) the <sup>523</sup> CLE. We now describe the different surfaces in more 524 details.



Variation of the 3d core level energies  $\varepsilon_{Sn,3d}$  as a FIG. 9. function of the position of the Sn atom in regard to the surface layer (S). The colored dotted lines indicates the averaged CLS  $\langle \varepsilon_{Sn,3d} \rangle$ .

525 the band structure given in Fig. 2(a), we saw the presence 584 526 of a partially-occupied surface gap state with a mixed 585 527 528 529 530 oxydation degree by 0.26 e of the Sr atoms located at 588 as we mentioned, there are differences ranging from <sup>531</sup> the surface, as compared with the bulk, *i.e.* with an <sup>589</sup> 70 meV to 100 meV. The origin of these shifts is not <sup>532</sup> increase of the number of electrons, which will populate <sup>590</sup> easy to determine and it is difficult to rule out they can

<sup>533</sup> 4d orbitals of these atoms. From Fig. 9, we can also notice <sup>534</sup> a decrease of the CLE  $\varepsilon_{Sn,3d}$ , that is the appearance of a 535 band bending and a local internal electric field between the atomic layers "S" and "S-1.5", also indicating a 536 transfer of electron to the  $\operatorname{Sn-}p$  orbitals. The CLE for  $\operatorname{Sn}$ 537 <sup>538</sup> atoms close to the center of the slab are tending toward <sup>539</sup> an averaged value 72 meV higher than the bulk CLE;  $_{540}$  this is consistent with the band structure of Fig. 2(a), in <sup>541</sup> which we can see that bulk states are above the Fermi 542 level, which is itself pinned by the surface states. When  $_{543}$  turning to a magnetic state, the Sn-3d CLE decrease by approximately 90 meV, mostly because of the lower lying 544 partly-occupied surface state of majority spin. 545

Adding an oxygen atom at the  $(2 \times 1)$  Sr<sub>2</sub>O surface 546 restores the bulk properties. It can indeed be seen that the calculated oxidation degree of the surface Sr atoms 548 is +1.14 e, *i.e.* closer from the bulk value of +1.24 e. 549 The averaged CLE, mostly representing bulk-like states, <sup>551</sup> remains the same for this structure as for the perfect surface, while we can see an increase of the CLE for the 552 subsurface atoms because of a shift of the Fermi level, 553 which is consistent with a depopulation of the surface 554 bands. 555

For the perfect SrSn termination, the charge balancing 556 is obtained by distributing holes on Sn-p orbitals, which <sup>558</sup> can be directly seen from the increase of the CLEs of the Sn atoms, while the oxidation degree of Sr atoms 559 560 does not change significantly. Due to the less correlated nature of these bands, a part of these charges is localized 561 near the surface, while the rest is spread over the whole 562 slab. Because the SrSn surface is hole doped, while the 563  $_{564}$  Sr<sub>2</sub>O surface is electron doped, we observe an internal electrical field which induces an opposite variation of the 565 CLS [See Fig. 9]. 566

For the three surface terminations described up-to-567 now, we saw that the charge reconstructions are mostly 568 involving surface atoms, and the CLEs in the center of 569 the slab are converging toward similar values (between 70 and 100 meV). The situation is different when Sn571 vacancies are present at the SrSn-terminated surface: 572 While the CLE of Sn atoms at the surface is of 0.12 eV, it is well lower for every other Sn atom (in particular Sn 574 atoms in the (S-1) layer) and the CLS of atoms in the 575 center of the slab reach a value close to the average, *i.e.* -0.05 eV. The occupied d states at the M point observed 577 in the band structure agree with the small diminution, 578 by 0.1 e, of the Bader charge of the surface  $[Sr]_{Sn}$  atom. 579  $_{580}$  This decrease is larger for the subsurface  $[Sr]_O$  atoms:  $_{581}$  The oxidation degree is calculated to be +1.03 e, when  $_{582}$  averaged on all the 4 [Sr]<sub>O</sub> ions and it is -0.97 e if we Fisrt, we can consider the perfect Sr<sub>2</sub>O surface. From 583 consider only the two [Sr]<sub>O</sub> ions, first neighbors of the Sn vacancy.

To finish this analysis, we would like to point out character associated with Sn-p and Sr-d orbitals. This 556 that, ideally,  $\Delta \varepsilon_{Sn,3d}$  should approach zero at the center observation is in agreement with the decrease of the 587 of each slab, *i.e.* recover the bulk value. However,

<sup>591</sup> originate from methodological artifacts, because of the <sup>592</sup> choice of the slab geometry and its limited thickness, for  $_{593}$  example. An explanation for the lowest value (-50 meV),  $_{594}$  calculated for the  $SrSn_{0.5}$  surface termination, will be <sup>595</sup> given in the next section.

#### VI. DISCUSSION

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Stability of the surface terminations and atomic 597 a.reconstructions: In their first-principles study, Bilal 598 et al. [31] already proposed, using another formalism. 599 that a perfect SrSn(001)-terminated surface of  $Sr_3SnO$ 600 is energetically more stable than a  $Sr_2O$ -terminated 601 one. The authors also suggested that due to the small 602 <sup>603</sup> energy difference, both terminations could be present in polycrystalline samples. Our calculations confirm this 604 prediction. Among the possible contributions, which 605 would help minimizing the surface energy, we can note 606 that the SrSn termination allows a higher cation-anion buckling. Such buckling results in the creation of 608 609 electric dipoles partially cancelling the internal electric 610 field close to the surface, which is a consequence <sup>611</sup> of the charge discontinuity associated with the polar  $_{612}$  nature of Sr<sub>3</sub>SnO(001). We also enlarged our study by <sup>613</sup> considering the variations of chemical potentials, which <sup>614</sup> can be related to experimental growth conditions, and by <sup>615</sup> proposing simple surface reconstructions. We then found <sub>616</sub> that a  $(2 \times 1)$  SrSn<sub>0.5</sub> surface can be stable in Sn-poor 617 conditions, which are still favorable to the growth of bulk  $Sr_3SnO$ . Finally, perfect or defectives  $Sr_2O$ -terminated 618 <sup>619</sup> surfaces could be obtained in oxygen-rich conditions.

Using the formula given in Ref. [22], it is possible 620 to calculate core-level shifts (CLS) from the CLEs, 621 which correspond, in this case, to the difference of 622  $_{623}$  binding energies between Sn-3d states in Sr<sub>3</sub>SnO and  $_{624}$  in bulk  $\alpha$ -Sn metal. For the  $Sr_2O_{1.5}$  and  $SrSn_{0.5}$ <sup>625</sup> surfaces, CLSs are in agreement with the CLSs measured  $_{626}$  by XPS: Reported experimental values are -1.10 eV  $_{627}$  and -1.05 eV, while calculated values for Sn atoms  $_{628}$  in the surface layer, are -1.12 eV and -1.07 eV, This tends to validate our model and 629 respectively. <sup>630</sup> suggests that these surface terminations may be present 631 in their studied samples, which would be an interesting 632 point to verify. The experimental finding of neutral 633 Sn atoms near the surface [22, 23] may indicate that 634 other possible reconstructions could be present, leading 658  $_{635}$  to the formation of other compounds than the Sr<sub>3</sub>SnO 636 antiperovskite, like metallic Sn clusters.

b. Electronic reconstructions: Considering the four 661 637  $_{638}$  most probable surface terminations, *i.e.* Sr<sub>2</sub>O, Sr<sub>2</sub>O<sub>1.5</sub>,  $_{662}$  $_{\rm 639}~SrSn$  and  $SrSn_{0.5},$  we can now discuss the electronic  $_{\rm 663}$ 640 reconstructions, associated with charge transfer and 664 <sup>641</sup> redistribution or to the presence of point defects. For the <sup>665</sup> 642 perfect surfaces, because we used an electrically-neutral 666 643 and nonstoichiometric structure with two equivalent 667 644 surfaces, either with a Sr<sub>2</sub>O or a SrSn termination, 668 645 respectively two electrons or holes are expected to be 669

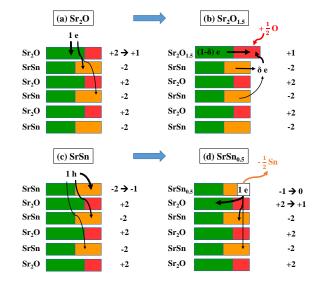


FIG. 10. Proposed diagrams showing the charge reconstruction at the four perfect or defective surfaces. The thickness of the arrows is approximately related to the amount of charges (electrons ("e") or holes ("h")) involved in the reorganization. The formal electric charges given on the right side of each atomic layers are approximated values before and after the electronic reconstruction (neglecting the charge extension away from the surface). The electronic reconstruction at the defective surfaces (b) and (d) may be explained relatively to the perfect surfaces (a) and (c). Green, orange and red squares represents the amount of Sr, Sn and O atoms. It is assumed that we consider a symmetric slab. Only a limited number of layers of a half of the slab is shown for the sake of simplicity.

646 re-distributed inside the structure and to either spread 647 in the entire slab by populating bulk bands, or to be <sup>648</sup> equally localized at the two surfaces, leading to  $(Sr_2O)^+$  $_{649}$  or  $(SrSn)^-$  terminations, this in order to preserve the 650 electrical neutrality. A different mechanism involving <sup>651</sup> charge transfer between the two different surfaces would 652 settle if we used an asymmetric slab instead, but <sup>653</sup> equivalent results are obtained for the perfect surfaces, 654 as discussed in Appendix B.

For each surface, the main conclusions are summarized 655 656 in Fig. 10 and explained below:

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1. In the case of the electron-doped  $Sr_2O$ -terminated surfaces, an extra electron per f.u. is partly localized at the surface and will mostly populate the partially-occupied gap states, as it can be seen in the DOS and band structures of Fig. 2. These surface bands have mostly a contribution coming from 4d orbitals of Sr atoms, as witnessed by the lower oxidation degree, but also of p orbitals of Sn atoms in further atomic layers. The electron localization in surface Sr-4d orbitals can lead to the stabilization of a magnetic state, with a total spin magnetic moment of 0.84  $\mu_{\rm B}$ /surface f.u. As proposed in Fig. 10(a), in first approximation, that

is, if we omit partial charges occupying some bulk 726 670 Sn-p bands, the localization of the extra electron  $_{727}$ 671 would then turn the  $[Sr_2O]^{2+}$  surface layer into 728 672  $[Sr_2O]^+$ . The electron doping can originate from 729 673 the off-stoichiometric structure or from a charge 730 674 balancing between the polar surface and a second 731 675 surface or an interface [See Appendix B]. This 732 676 interesting feature could enable to generate spin-733 677 polarized two-dimensional electron gases (2DEG), 734 678 owing to the relatively low effective masses we 735 679 calculated [See Table II in Appendix B]. 680 736

2. The  $Sr_2O_{1.5}$  surface, in which an oxygen adatom is <sub>738</sub> 681 introduced, is energetically favorable for samples 682 739 grown in oxygen-rich environment. This extra 740 683 oxygen atom will transform into a negatively-741 684 charged  $O^{2-}$  ion by attracting two electrons. Such <sub>742</sub> 685 scenario may provide another way to preserve the 743 686 electric neutrality and, in the same time, to add 744 687 one electron per f.u. to the surface, without 745 688 inducing charge transfer to the 4d bands of Sr  $_{746}$ 689 atoms [See Fig. 10(b)]. This statement is confirmed 747 690 by the Bader charge, which stays close to the one 691 748 calculated for the bulk compound and also by the 692 band structure which displays less occupied surface 693 states. As it can be seen on the 3d CLE variation 694 displayed in Fig. 9, a part of the charge attracted 695 by the oxygen atom to form the  $O^{2-}$  anion is 696 taken from the Sn bands, which are thus moving 697 upward in energy. Surface bands of  $\operatorname{Sn-}p$  orbital 698 character also display an hybridization with the 699 oxygen adatom orbitals, this one being located on 700 top of one of the Sn atom from the subsurface layer. 701

702 703 704 705 706 707 708 709 710 711 712 713 two-dimensional hole gas (q2DHG). 714

715 716 717 718 719 termination. 720 721 722 723 724 725

occupied Sr orbitals are those of Sr atoms of the subsurface layer (S-0.5) and not of the surface layer (S). The electronic reconstruction indeed does not involve the surface atomic layer, which is predicted to be electrically neutral, in agreement with the calculated value of the CLE of surface Sn ions (which is close from the averaged values calculated for the other surfaces). The band structure also shows that the bottom of the bulk conduction bands is crossing the Fermi level, inducing a total closure of the band gap at the  $\Gamma$  point, which would indicate that the remaining electron is transferred to the bulk. This occupation of bulk states is consistent with the calculated Sn CLEs in the center of the slab, which tends to a lower value in the center of the slab than the three other surfaces. In this scenario, both bulk and surface states are expected to participate to transport properties. As shown in Fig. 10(d), we thus propose a scenario in which the Sn vacancies at the surface are transferring charges mostly to the first-neighbor  $Sr_2O$  layer, but also partly to other inner layers.

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To summarize, we proposed 4 different surfaces, 2 <sup>749</sup> being hole-doped (with SrSn and  $Sr_2O_{1.5}$  terminations) <sup>750</sup> and the 2 others being electron-doped. For every  $_{751}$  interface, we observed clear surface states in the band gap of Sr<sub>3</sub>SnO and which cross the Fermi level. These bands 752 753 tend to spread away from the surface for wavevectors  $_{754}$  close to the  $\Gamma$  points, while they are associated with 755 carriers more confined in the surface layer for wavevectors <sup>756</sup> near the X and M points, in particular when they involve <sup>757</sup> 4d orbitals. The characterization of such surface states as <sup>758</sup> topological states would require a deeper analysis, which 3. The SrSn surface possesses a band structure with 759 is beyond the scope of the present paper. We can however a hole pocket around the M point (with a strong 760 notice that the calculated states are crossing the Fermi contribution from Sn atoms at the surface layer), 761 level and are joining the bulk valence and conduction as shown in Fig. 5. The variations of CLEs show,  $_{762}$  bands near the  $\Gamma$  point, as expected for topological however, that a part of the charge redistribution 763 states. These states may also look like projected states also affects Sn-p states deeper in the slab. This 764 calculated with a DFT+tight-binding method by Chiu, et process is summarized in Fig. 10(c). Again if 765 al. [15], who also predicted the possibility that such states we make the omission of the extension of the 766 would experience spin splittings. Finally, we showed surface state away from the surface, we can then 767 that these lifts of degeneracies require the presence of conclude that the [SrSn]<sup>2-</sup> surface is hole-doped <sup>768</sup> the spin-orbit interaction, which is not the case for and turned into a [SrSn]<sup>-</sup> surface. According to our 769 these surface states to exist, a property which has also calculations, such surface could then host a quasi- 770 been demonstrated in the case of topological crystalline 771 insulators [16].

c. Magnetic state: An important point in our results 772 4. Concerning the Sn-deficient  $SrSn_{0.5}$  surface, the  $\pi_3$  is that we demonstrated that the 2DEG could be spin counting of the total formal charges leads to the 774 polarized, with the formation of a FM ordering. The conclusion that with the proposed symmetric slab 775 stabilization of such magnetic ordering is consistent with geometry, we expect to have a redistribution of 1 776 earlier theoretical report of a magnetic state in Snelectron per surface f.u., as for the perfect Sr<sub>2</sub>O <sup>777</sup> deficient bulk Sr<sub>3</sub>SnO [See Ref. [30] and Appendix D 3]; The band structure in Fig. 8(b) 778 indeed, our symmetric slab with two equivalent Sr<sub>2</sub>O shows indeed that one surface gap state is 779 surfaces also corresponds to a Sn-deficient structure almost completely filled, suggesting some charge 780 with one missing SrSn(001) atomic layer. However, it localization near the surface, with a mixed Sn-p and 781 is not probable that such ordering would remain at  $[Sr]_{\Omega}$ -d character, as a function of the considered 782 room temperature. It seems moreover clear from our wavevector. First, it is important to note that the 783 calculations that it is not robust versus the presence of

<sup>784</sup> atomic defects or any change of the surface termination. <sup>842</sup> the above-mentionned experimental measurements [22]. <sup>765</sup> More surprisingly, the SrSn<sub>0.5</sub> surface is also found to <sup>843</sup> Sr vacancies are particularly interesting because they 786 be nonmagnetic, while containing Sn vacancies, which 844 are associated with the emergence of a superconductive 787 may indicate a more complex physics, related with 845 behavior for a temperature below 5 K and resulting from  $_{789}$  subsurface layer and not at the surface. Sr<sub>3</sub>SnO is not  $_{847}$  that Cooper pairs could have either a pure p-p orbital <sup>791</sup> as other examples have been studied and the subject <sup>849</sup> calculations, at least in the vicinity of a Sr-deficient 792 of debate for several years now.  $_{793}$  the example of the famous LaAlO<sub>3</sub>/SrTiO<sub>3</sub>, in which a  $_{851}$  and being doped by holes, to possess mostly a pure p ferromagnetic state has first been evidenced in 2007 [44]. 852 character. 794 Some studies have suggested that it may result from 795 <sup>796</sup> the presence of localized 3d gap states induced by the presence of defects [45, 46]. If the exact origin of 797 the magnetic ordering at this interface is subject to 798  $_{799}$  debate, it has been noticed both the TiO<sub>2</sub> and SrO <sup>800</sup> interface terminations can display ferromagnetism [47]. <sup>801</sup> The physics of magnetic  $d^0$  systems has often been <sup>802</sup> compared with the establishment of ferromagnetism in <sup>803</sup> diluted ferromagnetic semiconductors (DMS). Induced <sup>804</sup> ferromagnetic ordering has been already reported or <sup>805</sup> predicted in other dopant-free (*i.e.* without the addition <sup>806</sup> of impurities) bulk materials such as TiO<sub>2</sub>, SrTiO<sub>3</sub> <sup>807</sup> or ZnO [48, 49], but also in compounds presenting  $_{808}$  less localized unoccupied 4d or 5d orbitals, such as  $\alpha$ - $BOP PbO, In_2O_3, SnO_2, ZrO_2 \text{ or } HfO_2 [49-56]$ : In general, <sup>810</sup> the magnetic ordering is obtained by either changing <sup>864</sup> SrSn<sub>0.5</sub> surfaces. Each surface displays clear gap states <sup>811</sup> the stoichiometry, by adding interstitials or vacancies, <sup>\$12</sup> and/or by considering surfaces or confinement effects; <sup>\$13</sup> while electron-doped materials result in partially filled  $_{814}$  d orbitals, filling oxygen p orbitals with holes may also  $_{868}$  dimensional system. We found that electronic or atomic <sup>815</sup> induce ferromagnetism [50, 57]. The case of oxygen-<sup>869</sup> reconstruction favoring electron transfer to the surface  $_{816}$  deficient  $ZrO_2$  is particularly interesting, as it has been  $_{870}$  induce the presence of mixed Sn-p and Sr-d states, while <sup>\$17</sup> shown that the ferromagnetic ordering was more likely to <sup>\$71</sup> hole transfer implies that only pure p states will cross the <sup>\$18</sup> form in thin films or nanoparticles. Albanese, et al. [55] <sup>\$72</sup> Fermi level. <sup>819</sup> demonstrated that in nanoparticles the magnetic state <sup>873</sup> 820 only forms if the number of low-coordinated Zr atoms is 874 termination, the surface could host a ferromagnetic <sup>821</sup> sufficient in regard to the number of excess and available <sup>875</sup> ordering, due to the occupation of the Sr-4d orbitals. 822 charges. They also found that the ferromagnetic ordering 876 This ordering is however not expected to be robust as <sup>823</sup> is favored by the hybridization between the gap states <sup>877</sup> we have shown that it can be destroyed by the addition 824 and the bands at the bottom of the conduction bands. 878 of defects. On the contrary, the lack of spatial inversion 825 Applied to our system, such explanation could match 879 symmetry induced by the surface, is suitable to the with our observations. 826

d. Other surfaces: Finally, even if other surface 827 terminations are predicted to be less stable, we cannot 828 <sup>829</sup> discard that they could be obtained. It is important 830 to keep in mind that growth mechanisms rely on 831 out-of-equilibrium processes and that our calculated <sup>832</sup> results are given for a specific exchange-correlation-<sup>833</sup> energy functional. In addition, post-treatment like 834 chemical treatments or post-annealing could be used 885 to select a specific termination. 835 836 can mention the surface with a SrSn termination and 887 the framework of the Programme des Investissements <sup>837</sup> an oxygen vacancy in the subsurface layer, which <sup>888</sup> d'Avenir. H.J., C.P. and L.B. thank the Vannevar sss could be grown in oxygen-poor conditions, or the sss Bush Faculty Fellowship (VBFF) from the Department  $_{s39}$  Sr<sub>1.5</sub>O termination, which possess Sr vacancies with  $_{s90}$  of Defense. This work was granted access to the <sup>840</sup> a relatively low formation energy [See Table IV] and <sup>891</sup> HPC resources of CALMIP (Allocation No.  $_{841}$  calculated CLSs ( $\simeq -1.05$  eV) which also match with  $_{892}$  2021/P1229).

the fact that occupied Sr-d bands are located in the <sup>846</sup> hole doping. In their study, Oudah, et al. [18], proposed the first  $d^0$  oxides which would exhibit ferromagnetism, see character or a mixed p-d character. According to our We can first cite 850 surface, we expect the bands crossing the Fermi level

#### CONCLUSION VII.

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To summarize, we performed a study, as complete as 854  $_{855}$  possible, of the Sr<sub>3</sub>SnO(001) surface states. We identified <sup>856</sup> different surface terminations, which could be stable <sup>857</sup> depending on the growth conditions, and we predict that <sup>858</sup> SrSn-terminated surfaces are more likely to be obtained  $_{859}$  using suitable conditions for the growth of the Sr<sub>3</sub>SnO 860 antiperovskite.

We detailed the electronic properties of four 861  $_{862}$  terminations, which are the perfect  $Sr_2O$  and SrSnterminations and the  $(2 \times 1)$  reconstructed Sr<sub>2</sub>O<sub>1.5</sub> and <sup>865</sup> with a strong surface contribution around the X and <sup>866</sup> M wavevectors, indicative of a two-dimensional carrier <sup>867</sup> localization, which could lead to the emergence of a two-

Finally, we found that in the case of a perfect  $Sr_2O$ <sup>880</sup> appearance of Rashba-like spin splittings, which could be <sup>881</sup> another interesting feature of this interface, as it could <sup>882</sup> be used in applications based on spin-to-charge current 883 conversions.

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# **Appendix A: Bulk calculations**

894 <sup>895</sup> cubic bulk Sr<sub>3</sub>SnO is  $a_0(Sr_3SnO) = 5.10$  Å, *i.e.* -0.4%lower than the experimental parameter of 5.12 Å [12]. 896 897 If the spin-orbit interaction is switched-off, the band structure of bulk  $Sr_3SnO$  shows that a band with a 898  $\operatorname{Sn-}p_{\mu} + ip_z$  character crosses the Fermi level in the  $\Gamma$ -899  $_{900}$  X,  $\Gamma\text{-M}$  and  $\Gamma\text{-R}$  directions . As reported in Ref. [13] 901 and shown in Fig. 11, when including the spin-orbit  $_{902}$  interaction, the band structure is gapped in the  $\Gamma$ -M and  $_{903}$   $\Gamma$ -R directions and only two bands (omitting the spin 904 degeneracy), with  $\operatorname{Sn-}p_u + ip_z$  and  $\operatorname{Sr-}d_{u^2-z^2}$  characters,  $_{905}$  are forming an anticrossing at the Fermi level in the  $\Gamma$ -X <sup>906</sup> direction forming a pseudo-Dirac point. This anticrossing <sup>935</sup> <sup>907</sup> is characterized by the presence of a small band gap of 7 908 meV.

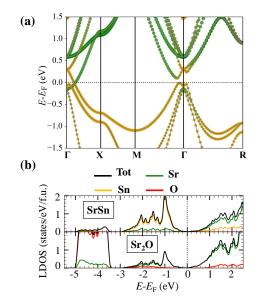


FIG. 11. Electronic structure of bulk Sr<sub>3</sub>SnO calculated with the PBESol functional and the spin-orbit interaction: (a) Band structure for which the high-symmetry points have the colors.

909 <sup>910</sup> correlation functional on the bulk electronic properties <sup>965</sup> polar character of Sr<sub>3</sub>SnO leads to the appearance of an 911 of Sr<sub>3</sub>SnO. In Ref. [58], Vidal, et al., warned that using 966 internal electric field for a thin film and an electronic 912 standard DFT functional could lead to false positive 967 reconstruction above a critical thickness following a 913 914 915 916 917  $_{918}$  more-demanding functionals. In the  $\Gamma$ -M direction, using  $_{973}$  the conduction band and the top of the valence band, at <sup>919</sup> the PBESol functional, we calculated a band gap width <sup>974</sup> each thin-film extremity, cross the Fermi level, causing a  $_{920}$  equal to 39 meV at the d-p antricrossing. We found  $_{975}$  Zener breakdown, *i.e.* a charge balancing by tunnelling <sup>921</sup> that the semi-metallic character is preserved with other <sup>976</sup> of electrons from the p-type to the n-type surface. This <sup>922</sup> functionals, but the band gap is increased to 159 meV <sup>977</sup> charge transfer is in particular necessary to avoid the

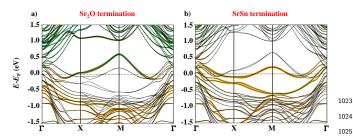
<sup>923</sup> with the SCAN functional [59], and to 122 meV or  $_{924}$  146 meV, using a PBESol+U [60] functional, with the The calculated equilibrium lattice parameter of the  $_{925}$  U-dependent correction applied on the 4d bands of Sr  $_{926}$  atoms and U = 1 eV or U = 2 eV, respectively. Finally, <sup>927</sup> when using the hybrid functional HSE06 [61], the band  $_{928}$  crossing is shifted toward the  $\Gamma$  point, which results in a <sup>929</sup> closing of the band gap at this same point, this results is <sup>930</sup> in agreement with the calculations reported in Ref. [14]. 931 Unfortunately, the use of such functional is too time <sup>932</sup> consuming to proceed to a more general comparison with 933 surface calculations.

#### Appendix B: Dependence on the choice of the slab 934 geometry

As explained in Section II, we proposed to describe 936 937 mostly our results issued from calculations performed with a symmetric slab, *i.e.* formed with two 938 equivalent surfaces. By construction, such a slab is 939 non-stoichiometric, which may have consequences in 940 particular for the study of polar materials. On the <sup>942</sup> contrary, such geometry has the advantage to be able to consider only one interface at a time, which is convenient to compare the relative surface stabilities, but also to avoid artifactual atomic relaxations or charge 945 transfers from a second interface, which is present using asymmetric slabs [See also the discussions in the supplemental material of Ref. [62]]. In this section, 948 we will describe the main differences which can be expected regarding the choice of the geometry. To do so, in addition to the  $(1 \times 1 \times 10.5)$  symmetric slab, we 951 performed calculations using an asymmetric slab. The 952 thickness of the new slab is of 6 layers of  $Sr_3SnO$  (12  $_{954}$  atomic monolayers) along the z[001] direction. When 955 optimizing the atomic structure, we fixed the positions 956 of the atoms located in the two monolayers the nearest from one interface and let the positions of all other atoms 957 relax. 958

By approximating the antiperovskite Sr<sub>3</sub>SnO as a 959 coordinates  $\Gamma(0,0,0)$ ,  $X(\frac{1}{2},0,0)$ ,  $M(\frac{1}{2},\frac{1}{2},0)$  and  $R(\frac{1}{2},\frac{1}{2},\frac{1}{2})$ ,  $_{960}$  fully-ionic compound formed of  $Sr^{2+}$  cations and  $O^{2-}$ (b) LDOS. The contribution of each atom are highlighted with  $_{961}$  and  $Sn^{4-}$  anions, we expect the (001) layer to be  $_{962}$  polar and constituted of an alternation of  $(Sr_2O)^{2+}$  and  $_{963}$  (SrSn)<sup>2-</sup> atomic layers. For an asymmetric film, with We also tested the influence of the exchange- $_{964}$  the combination of a SrSn and a Sr<sub>2</sub>O surfaces, the predictions of topological nature of some materials 968 polar catastrophe scenario, similarly to the processes because of the underestimation of the band gap and the 969 proposed for polar-oxide-based heterostructures like the wrong determination of the relative energies between  $p_{970}$  LaAlO<sub>3</sub>/SrTiO<sub>3</sub>(001) interface [26, 27]: Above a certain and d bands. For this reason, we performed, for the  $g_{11}$  thickness, because of the electric-potential build-up bulk structure only, calculations using computationally 972 associated with the internal electric field, the bottom of <sup>979</sup> layer thickness. For Sr<sub>3</sub>SnO, we can expect the transfer  $_{1019}E_{\text{field}} = \frac{\delta \varepsilon_{Sn,3d}}{e\delta z}$ , obtained by fitting the variation of <sup>980</sup> of 1 electron per formula unit (f.u.) from the  $[\text{SrSn}]^{2-}_{1020}$  CLE in the center of the slab, are  $-11 \text{ meV} \text{ Å}^{-1}$  and <sup>981</sup> to the  $[\text{Sr}_2\text{O}]^{2+}$  surface, in order to cancel the potential  $_{1021}$  +16 meV Å<sup>-1</sup>, respectively for the Sr<sub>2</sub>O- and SrSnbuild-up divergence; the band gap of  $Sr_3SnO$  being very  $_{1022}$  terminated interfaces. low, the electronic reconstruction would be present for 983 the lowest thickness. 984

In addition to the electronic reconstructions, other 985 <sup>986</sup> mechanisms have been proposed to explain the insulatorto-metal transition at polar interfaces, such as atomic 987 reconstructions involving the formation of structural 988 defects [46]. In the case of a symmetric slab, no internal 989 electric field can appear between the two equivalent 990 surfaces but the total atomic structure being non 991 stoichiometric, the excess of positive or negative charges 992 carried by the additional  $[Sr_2O]^{2+}$  or  $[SrSn]^{2-}$  atomic 993 <sup>994</sup> layer directly triggers the electronic reconstruction by <sup>995</sup> redistributing the excess of positive or negative charges. <sup>996</sup> This process would create surfaces carrying less, but non <sup>997</sup> zero, electric charges,  $[Sr_2O]^+$  or  $[SrSn]^-$ .



Band structure calculated with the spin-FIG. 12. orbit interaction for the (a) Sr<sub>2</sub>O-terminated and (b) SrSnterminated surface. The same color code is applied as in Fig. 2. When comparing with the band structure of Fig. 2 and 5, we can see that additional bands appear, which are the bulk positions.

998  $_{999}$  redistribution are then different depending on the  $_{1036}$  non-equivalent and reduces the space group to Pmmm1000 1001 1002 1003 Figs. 5(a) and 12(b), the band structures calculated for 1040 neither the spacial inversion symmetry nor the  $m_{001}$ 1004 1005 1006 1007 1008 1009 surface, independently of the chosen structure. This is 1046 can indeed notice many lifts of degeneracy, which can 1011 atoms located at the Sr<sub>2</sub>O or SrSn-terminated surface, 1048 shown in Figs. 3 and 6. We can see from these figures 1012 which are respectively 1.00 e or 1.26 e, in the asymmetric 1049 that the spin component is nul in directions parallel to <sup>1013</sup> slabs. The CLE  $\varepsilon_{Sn,3d}^{S}$  is also almost the same for both <sup>1050</sup> the wavevector k and we also found it is zero in the z[001]1014 slabs at the surface, that is respectively 0.17 eV and 1051 direction, which is the polar axis (*i.e.* the normal to the 1015 0.14 eV, while the average over the whole slab differs 1052 surface): These features are characteristics of the Rashba 1016 because of the second surface, which induces the presence 1053 effect. To characterize the energy spin splitting in a <sup>1017</sup> of a residual internal electric field, as it can be seen <sup>1054</sup> simple manner (without considering the point group),

978 divergence of the potential build-up as a function of the 1018 in Fig. 13. The values of these internal electric fields

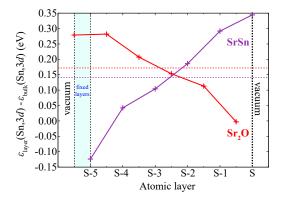


FIG. 13. Variation of the 3d core level energies  $\varepsilon_{Sn,3d}$  as a function of the position of the Sn atom in regard to the surface layer (S). The colored dotted lines indicates the averaged CLE  $\langle \varepsilon_{Sn,3d} \rangle$ . These results have been calculated using asymmetric slabs; they can be directly compared with those obtained with symmetric slabs and displayed in Fig. 9.

Beside the difference of stoichiometry, another question 1024 has to be addressed: It concerns the symmetries of our <sup>1025</sup> structures, in regard to the choice of slab geometry. <sup>1026</sup> This point is particularly important when considering 1027 spin-orbit effects. The bulk cubic perovskite structure 1028 possesses a  $Pm\overline{3}m$  (No 221) space group associated <sup>1029</sup> with a  $O_h$  point group. When building the symmetric 1030 slab, the space group changes to P4/mmm (No 123), the result of the presence of the second, non-equivalent and <sup>1031</sup> with the fourfold rotation axis parallel to the normal non-physical, surface, for which the atomic layers are fixed to 1032 to the (001) surface. Including a point defect on both <sup>1033</sup> surfaces with  $(\sqrt{2} \times \sqrt{2})$  dimensions [see Appendix D 3], 1034 does not change the space group, while using  $(2 \times 1)$ The mechanisms explaining the calculated charge 1035 dimensions makes x[100] and y[010] directions to become slab geometries, but the charge redistribution can be 1037 (No 47), with a two-fold rotation axis. Finally, asymetric nonetheless comparable for both configurations. As 1038 slabs with perfect Sr<sub>2</sub>O and SrSn surfaces will correspond it can be seen by comparing Figs. 2(a) and 12(a) or 1039 to a P4mm (No 99) space group, which does not possess both geometries appear indeed similar; the crossing of 1041 mirror symmetry. As already said, this lack of inversion the gap states with the Fermi level happens at almost 1042 symmetry, which would exist for real surfaces, allows the the same values of wavevector for both structures and 1043 apparition of an internal electric field, but also of Rashbathe band dispersions look similar, which suggests that 1044 like spin splittings in the band structure. Looking at an almost equal amount of charges is localized near the 1045 the fine details of the band structures of Fig. 12, we confirmed by the Bader charges calculated for the Sr 1047 be associated with Rashba-like spin splittings, as it was

TABLE II. Effective masses  $m^*$  and spin splitting parameters a and b calculated for the bands of energy E, the closest from the Fermi level at the X and M points.

| Direction                             | $E - E_{\rm F}$ | $m^*$   | a      | b          |
|---------------------------------------|-----------------|---------|--------|------------|
|                                       | (eV)            | $(m_0)$ | (eV Å) | $(eV Å^3)$ |
|                                       | $Sr_2O$ (       | termina | ation  |            |
| $X_{\to\Gamma}$                       | 0.042           | -0.54   | 0.10   | -2.2       |
| $\mathrm{X}_{\rightarrow \mathrm{M}}$ | 0.042           | 1.34    | 0.16   | -1.6       |
| $M_{\rightarrow X}$                   | 0.606           | -0.23   | 0.07   | 0          |
| $M_{\to\Gamma}$                       | 0.606           | -0.33   | 0.08   | -0.33      |
| SrSn termination                      |                 |         |        |            |
| $X_{\to\Gamma}$                       | -0.077          | 4.04    | 0.04   | 0.47       |
| $X_{\rightarrow M}$                   | -0.077          | -2.03   | 0.21   | -1.68      |
| $M_{\rightarrow X}$                   | 0.204           | -0.69   | 0.05   | -1.42      |
| $M_{\rightarrow \Gamma}$              | 0.204           | -0.88   | 0.05   | -2.48      |

<sup>1055</sup> it is possible to fit the difference between the energy 1090 1056 of the two bands of opposite spin  $\Delta E_{\pm}$  as a function  $_{1057}$  of the wavevector k by a third order polynom, such as 1058  $\Delta E_{\pm}(k) = a \cdot k + b \cdot k^3$  [63]. Around the M point of 1092 1059 little point group  $C_{4v}$ , the coefficient *a* corresponds to <sup>1060</sup> the linear Rashba coefficient multiplied by a factor 2  $_{1061}$  and the cubic term b can be decomposed into two terms <sup>1062</sup> [namely  $\gamma'$  and  $\gamma''$  in Ref. [64]]. The spin-splitting values 1063 fitted from our calculations around the X and M high-<sup>1064</sup> symmetry points are summarized in Table II. If the values <sup>1005</sup> of each coefficient remain modest, it can be noticed from <sup>1094</sup> where  $E_{X_3YZ}^{\text{bulk}}$  is the ground state total energy calculated <sup>1006</sup> the band structures that the spin splittings are enhanced <sup>1007</sup> in the vicinity of band anti-crossings. Interesting spin <sup>1096</sup> energies of the X, Y and Z atoms in their pure solid <sup>1097</sup> multiplication of the spin splittings are the total <sup>1068</sup> splittings can also be noticed near the  $\Gamma$  point, but due 1069 to the higher number of bands, mixing surface and bulk 1070 states, their analysis is more complex.

#### Appendix C: Effect of the spin-orbit interaction 1071

In this section, we provide the band structures 1072 1073 calculated for the two perfect surface terminations <sup>1074</sup> without the spin-orbit interaction; the band structures of <sup>1103</sup> with  $\Delta_{\rm f} H_{\rm B}$  the formation enthalpy of the bulk <sup>1075</sup> Fig. 14 can be compared with those of Figs. 2(a) and 5(a) <sup>1104</sup> antiperovskite, and by the following equations, which 1076 to understand the effect of this interaction.

#### Appendix D: Surface formation energy 1077

1078 1079 energy [65, 66] consists in

1. defining the chemical potentials ranges for which 1080 the considered bulk compound is stable, in regard 1081 to all the other possible competitive phases, 1082

1083 1084 1085 of formation. 1086

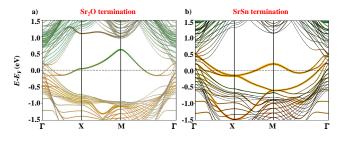


FIG. 14. Band structure calculated without the spinorbit interaction for the (a) Sr<sub>2</sub>O-terminated and (b) SrSnterminated surface. The same color code is applied as in Fig. 2.

This method is explained in the following for a general 1087 <sup>1088</sup> X<sub>3</sub>YZ perovskite compound and then applied in the  $_{1089}$  specific case of Sr<sub>3</sub>SnO.

#### 1. Enthalpy of formation of bulk Sr<sub>3</sub>SnO antiperovskite

The enthalpy of formation  $\Delta_{\rm f} H$  of an antiperovskite  $_{1093}$  of formula X<sub>3</sub>YZ can be expressed as:

$$\Delta_{\rm f} H \left( {\rm X}_3 {\rm YZ} \right) = E_{{\rm X}_3 {\rm YZ}}^{\rm bulk} - \sum_i N_i E_i^{\rm bulk/gas} \qquad ({\rm D1})$$

1097 or gas phase and  $N_i$  are the number of atoms of each 1098 chemical specy. In the antiperovskite compound, the 1099 chemical potentials  $\mu_i$  of these atoms may differ from <sup>1100</sup>  $E_i^{\text{bulk/gas}}$  by an energy  $\Delta \mu_i$ , *i.e.*  $\mu_i = E_i^{\text{bulk/gas}} + \Delta \mu_i$ . <sup>1101</sup> The conditions for the bulk antiperovskite to be stable <sup>1102</sup> are given by the following identity:

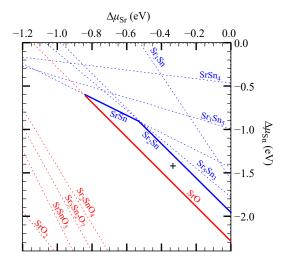
$$3\Delta\mu_{\rm X} + \Delta\mu_{\rm Y} + \Delta\mu_{\rm Z} = \Delta_{\rm f} H_{\rm B} \left( {\rm X}_3 {\rm YZ} \right) \tag{D2}$$

1105 need to be verified in order to avoid any competitive 1106 phase to form:

$$n_x \Delta \mu_{\rm X} + n_y \Delta \mu_{\rm Y} + n_z \Delta \mu_{\rm Z} \le \Delta_{\rm f} H_{\rm B} \left( \mathbf{X}_x \mathbf{Y}_y \mathbf{Z}_z \right) \quad (\mathrm{D3})$$

It is then possible to calculate a phase diagram, as 1107 The method used to calculate the surface formation 1108 proposed in Fig. 15, in which we can identify the couple 1109 of values of  $(\Delta \mu_{Y=Sn}, \Delta \mu_{X=Sr})$  for which Sr<sub>3</sub>SnO can <sup>1110</sup> be formed. In particular, knowing  $\Delta_{\rm f} H ({\rm Sr}_3 {\rm SnO})$  from <sup>1111</sup> Eq. D1, it is possible to notice that  $\Delta \mu_{\rm O}$  is always <sup>1112</sup> bound to  $\Delta \mu_{\rm Sr}$  and  $\Delta \mu_{\rm Sn}$  through the relation of Eq. D2. <sup>1113</sup> Moreover, the variation of chemical potential of the 2. searching for the most stable (001) surface 1114 oxygen atoms  $\Delta \mu_{\rm O}$  can be related to the experimental terminations in the bulk stability range of 1115 growth conditions, *i.e.* the temperature T and the chemical potentials, by comparing the enthalpies 1116 pressure P, using thermodynamical models as proposed 1117 in Refs. [66] and [67].

A first list of competitive phases has been established 1118 thanks to the Materials project database [68]; when 1119 several stable structures were reported for a given 1120 chemical composition, we selected the most stable one 1121 after a structural optimization performed keeping the 1122 <sup>1123</sup> same calculation parameters. The space groups are  $_{1124}$  computed using the *FINDSYM* program [69, 70] with <sup>1125</sup> a tolerance of  $10^{-3}$  Å applied on the atom coordinates 1126 and lattice parameters.



blue and red colors means that Sr<sub>3</sub>SnO is stable respectively below or above the given limit. This allows to define the stability domain delimited by the solid lines.

## 1127

#### 2. Surface energy

1128 1129 two identical surfaces, we express the surface energy  $\gamma_{\rm S}$ : 1169 terminations will be present in real samples, explaining

$$\gamma_{\rm S} = \frac{1}{2A} \left[ E_{\rm S} - \sum_i N_i \mu_i \right] \tag{D4}^{1171}$$

1131 two identical surfaces S of termination i and of area A. 1175 point defects. It is thus possible to define an energy of <sup>1122</sup> The chemical potentials  $\mu_i$  are those calculated in the <sup>1176</sup> formation of the defect, which is expressed as a function <sup>1133</sup> previous step, such as they are at equilibrium with the <sup>1177</sup> of the energy of the slab or bulk supercell: 1134 bulk.

It is also convenient to reformulate Eq. D4 explicitly <sup>1136</sup> as a function of  $(\Delta \mu_{\rm Y=Sn}, \Delta \mu_{\rm X=Sr})$ , which for the study <sup>1137</sup> of Sr<sub>3</sub>SnO surfaces gives:

$$\gamma_{\rm S} = \frac{1}{2A} \left[ \alpha + \beta \Delta \mu_{\rm Sr} + \zeta \Delta \mu_{\rm Sn} \right]$$
  
with  
$$\alpha = E_{\rm S} - \sum N_i E(i) - N_{\rm O} \Delta_{\rm f} H_{\rm B} \left( {\rm Sr}_3 {\rm SnO} \right) \quad ({\rm D5})$$

$$\begin{aligned} \lambda &= D_{\rm S} \sum_{i={\rm Sr},{\rm Sn},{\rm O}} N_i D(i) \quad N(0\Delta_{\rm F} HB ({\rm Sr}_3 {\rm SnO})) \quad (DS) \\ \beta &= 3N_{\rm O} - N_{\rm Sr} \\ \zeta &= N_{\rm O} - N_{\rm Sn} \end{aligned}$$

By comparing the surface energy  $\gamma_{\rm S}$  calculated for 1138 <sup>1139</sup> different surface terminations, it is possible to determine which atomic structure is the most stable for a selected 1140 couple of values  $(\Delta \mu_{\rm Y=Sn}, \Delta \mu_{\rm X=Sr})$ ; interesting couples of values will be in particular those for which bulk Sr<sub>3</sub>SnO 1142 is stable. 1143

As mentioned in Refs. [71–73], calculating surface 1144 energies of polar oxides requires a lot of care and it is 1145 important to verify the convergence as a function of the 1146 vacuum and film thicknesses and of the k mesh used 1147 <sup>1148</sup> for the first Brillouin zone sampling, in order to ensure a good convergence of the energy as a function of the 1149 slab thickness (the reader can refer to Ref. [73] for more <sup>1151</sup> information about the different methods to circumvent <sup>1152</sup> such a problem). Performing our calculations, we <sup>1153</sup> verified that the 2D k-mesh sampling used for the  $_{1154}$  (001) slabs was matching with those used for the bulk FIG. 15. Stability phase diagram of bulk Sr<sub>3</sub>SnO oxide. Red 1155 calculations and we also checked that, by varying the slab and blue lines correspond to the constrain given by Eq. D3, 1156 thickness, we have a precision of 5 meV on the surface 1157 energy. Another critical point, which is standard in <sup>1158</sup> DFT calculations, arises from the choice of the exchange-<sup>1159</sup> correlation functional. In particular, it has been pointed  $_{1160}$  out that the binding energy of the  $O_2$  molecule may be <sup>1161</sup> overestimated [71, 72], which would justify the need to <sup>1162</sup> correct the chemical potential of oxygen atoms by shifting <sup>1163</sup> its value. If applying such correction would change the <sup>1164</sup> calculated formation energies of Sr<sub>3</sub>SnO, the chemical 1165 potential of the oxygen atoms does not appear in the <sup>1166</sup> equation D5. Since different surface energies can display <sup>1167</sup> very close surface energies, depending on the growth Considering a slab formed by a symmetric layer with 1168 conditions, we can in any case expect that different <sup>1170</sup> why we decided to compare different terminations.

#### Energy of defect formation 3.

Another way to describe the previously mentioned 1172 1173 surface terminations is to consider that they correspond <sup>1130</sup> with  $E_{\rm S}$  the total energy of the slab of X<sub>3</sub>YZ comporting <sup>1174</sup> to the association of a perfect surface termination with

$$E_{\rm d} = E_{\rm sd} - \left(E_{\rm sp} + \sum_i N_i \mu_i\right) \tag{D6}$$

TABLE III. Formation energies of defects  $E_{d}$  calculated using the values:  $\Delta \mu_{\rm Sr} = -0.341$  eV,  $\Delta \mu_{\rm Sn} = -1.440$  eV and

| Surface dimension       | Type of defect    | $E_{\rm d}$ | $\langle \Delta \varepsilon_{Sn,3d} \rangle$ |
|-------------------------|-------------------|-------------|--|
|                         |                   | (eV/defect) | (eV)   |
|                         | Bulk              |             |  |
| $(2 \times 2 \times 2)$ | $V_{Sr}$          | 0.22        |  |
| $(3 \times 3 \times 3)$ | $V_{Sr}$          | 0.05        | 0.359  |
| $(2 \times 2 \times 2)$ | $V_{Sn}$ (NM)     | 0.32        |  |
| $(3 \times 3 \times 3)$ | $V_{Sn}$          | 0.09        | -0.276                                       |
| $(4 \times 4 \times 4)$ | $V_{\mathrm{Sn}}$ | 0.04        |  |
| $(2 \times 2 \times 2)$ | Vo                | 0.15        |  |
| $(3 \times 3 \times 3)$ | Vo                | 0.05        | -0.066                                       |

 $_{\rm 1178}$  with  $E_{\rm sd}$  and  $E_{\rm sp}$  the energies of the supercell 1179 respectively with and without the defect, and  $\mu_i$  = 1180  $E_i^{\text{bulk/gas}} + \Delta \mu_i$ . With this new equation again, the 1181 formation energy  $E_{\rm d}$  depends on the chosen values of <sup>1182</sup> the chemical potentials; taking the same averaged values 1183 as previously, we can then obtain the formation energies 1184 given in Table III and IV.

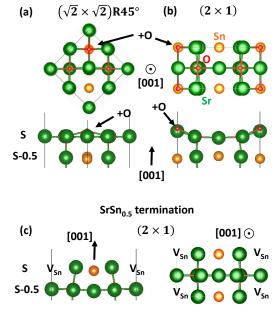
a. Formation of point defects in the bulk compound: 1185 We calculated the effect of vacancies in bulk supercells. 1186 The energies of formation, summarized in Table III, show 1187 that it is difficult to calculate an accurate energy for 1188 individual defects and that they strongly depend on the 1189 <sup>1190</sup> supercell size.

As calculated previously by Batool *et al.* [30], we 1191 found that a Sn vacancy induces the appearance of a 1192 ferromagnetic ordering by populating Sr-4d bands: We 1193 calculated a total magnetic moment of 1.04  $\mu_B$ , which is 1194 <sup>1195</sup> comparable to the value of 1.28  $\mu_B$  given in Ref. [30] and to the value calculated for the surface, *i.e.* 0.84  $\mu_B$ . This 1197 magnetic ordering is weak and is likely to be destroyed <sup>1198</sup> by the addition of defects at the surface. In the case of the bulk calculations, we found that it only appears for 1199 a very high content of vacancies, that is for the smallest 1200 <sup>1201</sup> supercell with  $2 \times 2 \times 2$  dimensions.

1202  $_{1203}$  in the previous paragraph, speaking of formation  $_{1219}$  rich Sr<sub>2</sub>O surface and for the Sn-deficient SrSn surface are 1204 energy of a defect is not rigorous because of the high 1220 given in Fig. 16.

1205 content of defects we considered; the concept of surface 1206 reconstruction is more adapted to this study. The  $\Delta \mu_{\rm O} = -5.484$  eV. For information, we also provide the <sup>1207</sup> formation energies given in Table IV, however, allows us averaged Sn-3d CLSs calculated with the  $3 \times 3 \times 3$  supercells.<sup>1206</sup> to have an idea of the energy difference separating the <sup>1209</sup> different surface terminations for a given set of chemical 1210 potentials.

> For the  $Sr_2O$  termination, we tested two different 1211 <sup>1212</sup> latteral dimensions to build our slabs:  $(\sqrt{2} \times \sqrt{2}) R45^\circ$  $_{1213}$  and  $(2 \times 1)$ . We can notice that the latter one gives almost 1214 systematically lower formation energies than the first <sup>1215</sup> one, which means that the  $(2 \times 1)$  geometry gives more 1216 stable structures when including defects. This explains



Optimized atomic structure (side and top view) FIG. 16. of the defective surface: (a) and (b) represent respectively the  $(\sqrt{2} \times \sqrt{2})$ R45° and  $(2 \times 1)$  Sr<sub>2</sub>O<sub>1.5</sub> surfaces, *i.e.* surfaces with a  $Sr_2O$  termination and an additional oxygen atom located in an interstitial position of the surface layer (S), (on top of a Sn atom from the subsurface layer (S-0.5)); (c) corresponds to a  $(2 \times 1)$  SrSn surface with a Sn vacancy.

<sup>1217</sup> why we only discuss this configuration in the main text. b. Formation of defects at the surface: As seen 1218 Examples of relaxed structures calculated for the oxygen-

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1255 TABLE IV. Formation energies of defects  $E_{\rm d}$  at the  $Sr_3SnO(001)$  surfaces. The calculations have been performed 1257 using Eq. D6 and with the variations of chemical potentials 1258 corresponding to the middle of the Sr<sub>3</sub>SnO stability domain given by the black cross in Fig. 15, *i.e.*  $\Delta \mu_{\rm Sr} = -0.341$  eV, 1260  $\Delta \mu_{\rm Sn} = -1.440$  eV and  $\Delta \mu_{\rm O} = -5.484$  eV. The defect "+O 1261 corresponds to an oxygen adatom located either in the surface 1262 layer (S) on top of the subsurface Sn atom, or initially on 1263 top (S+1) of a surface Sr atom. For the  $(2 \times 1)$ , there is 1264 two non-equivalent Sr atom (labeled "1" and "2"), which are 1265 respectively aligned with the oxygen atoms along the [010] 1266 and [100] directions (the [010] direction being twice shorter than the [100] direction, this may explain why the Sr1 vacancy is less stable than the Sr2 vacancy).

| Surface dimension  | Type of defect      | location     | $E_{\rm d}$ |  |  |  |  |
|--|---------------------|--------------|-------------|--|--|--|--|
|  |                     |              | (eV/defect) |  |  |  |  |
|  | $SrO_2$ termination |              |             |  |  |  |  |
| $\left(\sqrt{2} \times \sqrt{2}\right) \text{R45}^{\circ}$ | $V_{Sr}$            | $\mathbf{S}$ | 0.60        |  |  |  |  |
| $\left(\sqrt{2} \times \sqrt{2}\right) \text{R45}^{\circ}$ | $V_{Sr}$            | S-0.5        | 1.28        |  |  |  |  |
| $\left(\sqrt{2} \times \sqrt{2}\right) \text{R45}^{\circ}$ | $V_{Sn}$            | S-0.5        | 1.88        |  |  |  |  |
| $\left(\sqrt{2} \times \sqrt{2}\right) \text{R45}^{\circ}$ | $V_{O}$             | $\mathbf{S}$ | 0.61        |  |  |  |  |
| $\left(\sqrt{2} \times \sqrt{2}\right) \text{R45}^{\circ}$ | $+\mathrm{O}$       | $\mathbf{S}$ | 0.40        |  |  |  |  |
| $\left(\sqrt{2} \times \sqrt{2}\right) \text{R45}^{\circ}$ | $+\mathrm{O}$       | S+1          | 4.14        |  |  |  |  |
| $(2 \times 1)$   | $V_{Sr1}$           | $\mathbf{S}$ | 1.00        |  |  |  |  |
| $(2 \times 1)$   | $\rm V_{Sr2}$       | $\mathbf{S}$ | 0.40        |  |  |  |  |
| $(2 \times 1)$   | $V_{Sr}$            | S-0.5        | 0.99        |  |  |  |  |
| $(2 \times 1)$   | $V_{Sn}$            | S-0.5        | 1.77        |  |  |  |  |
| $(2 \times 1)$   | Vo                  | $\mathbf{S}$ | 0.54        |  |  |  |  |
| $(2 \times 1)$   | $+\mathrm{O}$       | $\mathbf{S}$ | 0.25        |  |  |  |  |
| SrSn termination   |                     |              |             |  |  |  |  |
| $(2 \times 1)$   | $V_{\rm Sr}$        | $\mathbf{S}$ | 2.09        |  |  |  |  |
| $(2 \times 1)$   | $V_{Sr1}$           | S-0.5        | 2.32        |  |  |  |  |
| $(2 \times 1)$   | $V_{\mathrm{Sr2}}$  | S-0.5        | 1.84        |  |  |  |  |
| $(2 \times 1)$   | $V_{Sn}$            | $\mathbf{S}$ | -0.21       |  |  |  |  |
| $(2 \times 1)$   | Vo                  | S-0.5        | 0.42        |  |  |  |  |

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